

HMIC PIN Diode Variable Attenuator
1.70-2.20 GHz

MA4VAT2000-1277T
V2

Features

- RoHs and ELV compliant
- Bandwidth: 1.70 GHz to 2.20 GHz
- 1.2 dB Insertion Loss, Typical
- 1.4:1 VSWR, Typical
- 24 dB Attenuation, Typical
- 40 dBm IIP3, Typical (1MHz Offset, @ +0dBm Pinc)
- 0-1.5 Volt Control Voltage.
- User can add an External Resistor for higher D.C. Voltage requirements.

Extra Features

- Usable Bandwidth: 1.20 GHz to 2.50 GHz
- 1.5 dB Insertion Loss, Max
- 2:1 VSWR, Max
- 23 dB Attenuation, Max

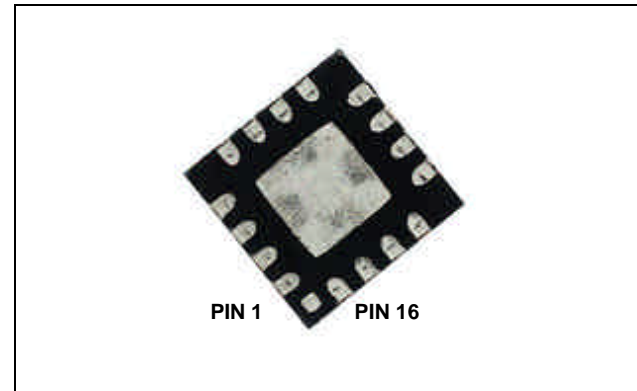
Description and Applications

M/A-COM's MA4VAT2000-1277T is a HMIC PIN Diode Variable Attenuator which utilizes an integrated 90 degree 3dB hybrid with a pair of Silicon PIN Diodes to perform the required attenuation function as Voltage (Current) is applied. This device operates from 0 to 1.5 Volts at 260 uA typical control current for maximum attenuation. The user can add external biasing resistors to the bias ports for higher voltage requirements as required.

M/A-COM's MA4VAT2000-1277T PIN Diode Variable Attenuator is designed for AGC Circuit Applications requiring:

- Lower Insertion Loss
- Lower distortion through attenuation
- Larger dynamic range for wide spread spectrum applications

MLP 3mm Package
(Circuit Side View)



PIN Configuration

| PIN | Function | PIN | Function |
|-----|----------|-----|----------|
| 1 | GND | 9 | DC2 |
| 2 | GND | 10 | GND |
| 3 | GND | 11 | GND |
| 4 | GND | 12 | DC1 |
| 5 | GND | 13 | GND |
| 6 | RF2 | 14 | GND |
| 7 | GND | 15 | RF1 |
| 8 | GND | 16 | GND |

Center Paddle is RF and D.C. Ground
RF Input/Output Ports are Functionally Symmetrical

Absolute Maximum Ratings^{1,2}

| Parameter | Maximum Ratings |
|--------------------------|-------------------|
| Operating Temperature | -40 °C to +85 °C |
| Storage Temperature | -65 °C to +150 °C |
| Junction Temperature | +175 °C |
| RF C.W. Incident Power | +33 dBm C.W. |
| Reversed Current @ -30 V | I -50nA I |
| Control Current | 50mA per Diode |

1. All the above are at Room Temperature except as noted
2. Exceeding the above Limits may cause permanent damage

**HMIC PIN Diode Variable Attenuator
1.70-2.20 GHz**

**MA4VAT2000-1277T
V2**

Electrical Specifications @ +25 °C

| Parameter | Frequency Band | Unit | Min | Typ | Max |
|--------------------------------------|---------------------|------|-----|---------------|-----|
| No DC Bias Low Loss State | | | | | |
| Insertion Loss | 1.70 GHz – 2.20 GHz | dB | - | 1.2 | 1.4 |
| Input Return Loss | | dB | 11 | 16 | - |
| Output Return Loss | | dB | 11 | 16 | - |
| P1dB | | dBm | 30 | 33 | - |
| IIP3 | | dBm | 37 | 40 | - |
| Control Voltage | | V | - | 0V @ 0uA | - |
| DC Bias RF Attenuation State | | | | | |
| Maximum Attenuation | 1.70 GHz – 2.20 GHz | dB | 23 | 25 | - |
| Input Return Loss @ Max Attenuation | | dB | 17 | 20 | - |
| Output Return Loss @ Max Attenuation | | dB | 17 | 20 | - |
| IIP3 | | dBm | 15 | 21 | - |
| Control Voltage @ Max Attenuation | | V | - | 1.50V @ 260uA | - |

Typical RF Performance Over Industry Designated RF Frequency Bands

| Band | | Freq | I. Loss | Att. | R. Loss | IIP3 | Phase -Relative- |
|------------|----|-----------|---------|------|---------|-------|---------------------|
| | | (MHz) | (dB) | (dB) | (dB) | (dBm) | (Degree) |
| DCS | RX | 1710-1785 | 1.2 | 23 | 13 | 40 | -20° |
| | TX | 1805-1880 | 1.2 | 23 | 13 | 40 | |
| PCS | RX | 1850-1910 | 1.2 | 23 | 13 | 40 | -20° |
| | TX | 1930-1990 | 1.4 | 23 | 13 | 40 | |
| UMTS | RX | 1920-1980 | 1.4 | 23 | 11 | 40 | -25° |
| WCDMA/CDMA | TX | 2110-2170 | 1.5 | 23 | 11 | 40 | |
| TD-S-CDMA | - | 2010-2025 | 1.4 | 23 | 11 | 40 | -25° |
| SCDMA | - | 1800-2200 | 1.8 | 23 | 11 | 40 | -25° |

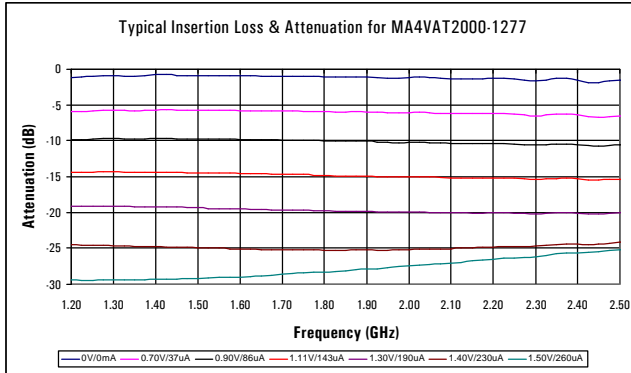
1. All are typical values only.
2. Relative phase is the measured Insertion Phase Difference between Insertion Loss and the 20dB Attenuation State.
(Please refer to the plots below)

**HMIC PIN Diode Variable Attenuator
1.70-2.20 GHz**

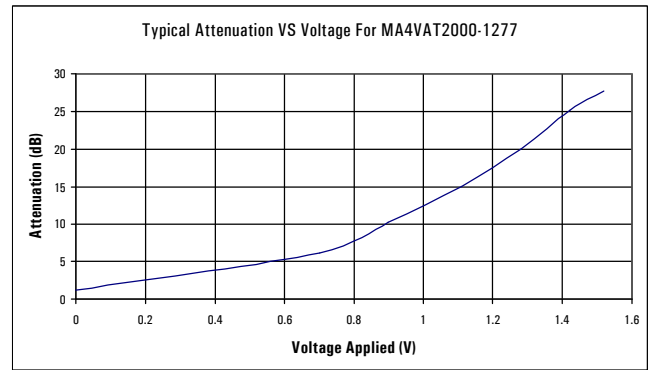
**MA4VAT2000-1277T
V2**

Plots of Typical RF Characteristics @ + 25 °C

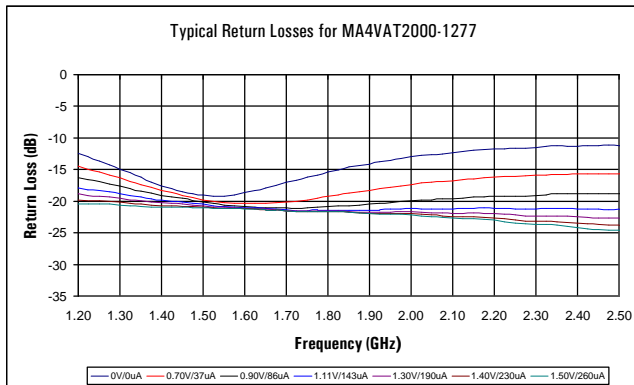
Typical Insertion Loss & Attenuation Plot



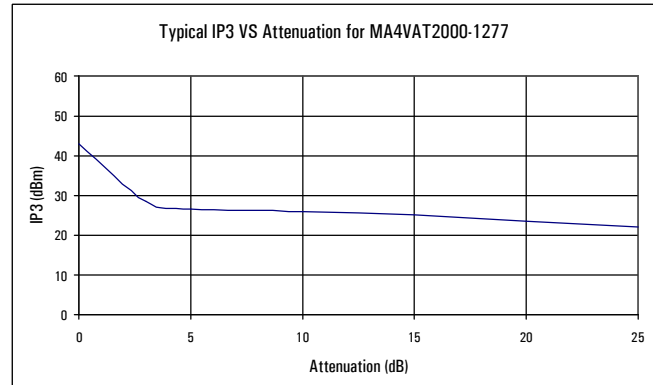
Typical Attenuation Vs Voltage Plot (@ 1950 MHz)



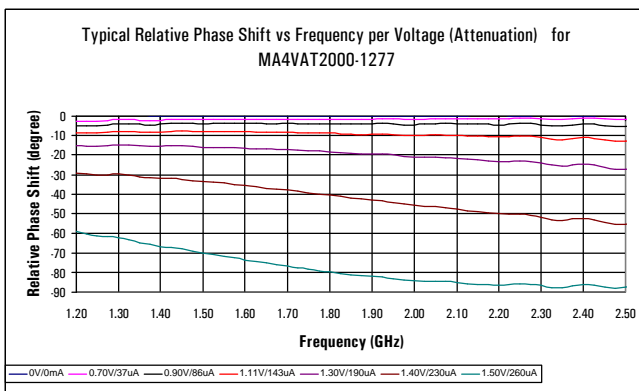
Typical Return Loss @ All Attenuation Levels Plot



Typical IIP3 Vs Attenuation Plot



Typical Relative Phase Shift Per Attenuation (Voltage) Plot



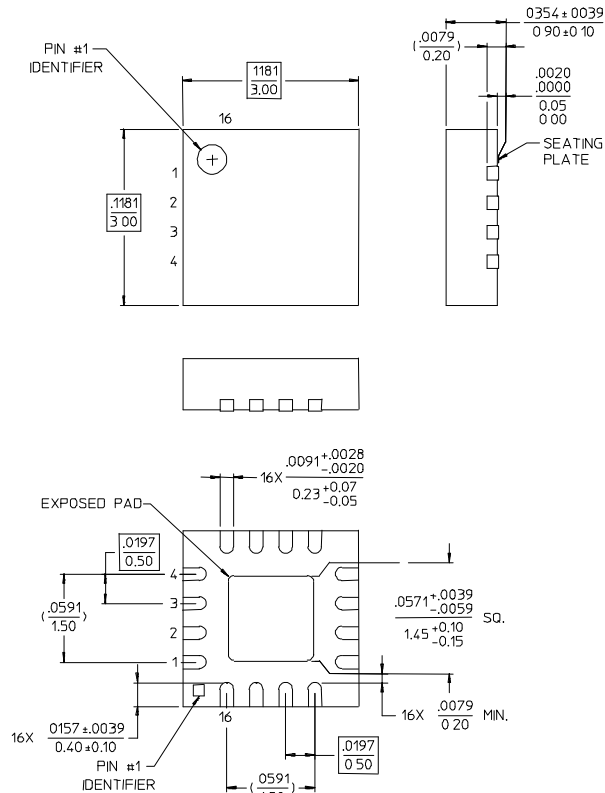
For Reference ONLY:

- Low Loss = 0V, @0uA
- 5 dB Attenuation = 0.90V, @86uA
- 10 dB Attenuation = 1.11V, @143uA
- 15 dB Attenuation = 1.30V, @190uA
- 20 dB Attenuation = 1.40V, @230uA
- 25 dB Attenuation = 1.50V, @260uA

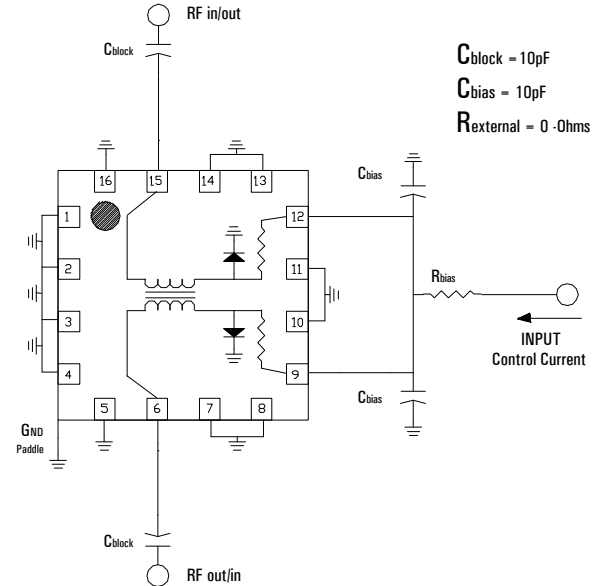
HMIC PIN Diode Variable Attenuator
1.70-2.20 GHz

MA4VAT2000-1277T
V2

Package PIN Designation, External Components, and Equivalent Circuit



NOTES: 1. RBFBRNCB JBDBC M0-220, VAR. VBBD-1 FOR ADDITIONAL DIMENSIONAL AND TOLERANCE INFORMATION.
2. RBFBRNCB S2083 APPLICATION NOTE FOR PCB FOOTPRINT INFORMATION
3. ALL DIMENSIONS SHOWN AS INCHES/MM



$C_{block} = 10\text{pF}$
 $C_{bias} = 10\text{pF}$
 $R_{external} = 0\text{-}\Omega$

Ordering Information

| Part Number | Package |
|------------------|---------------|
| MA4VAT2000-1277T | Tape and Reel |